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| APPLICATION NO. | FILING DATE | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO. | CONFIRMATION NO. |
|--------------------|---|----------------------|---------------------|------------------|
| 10/659,748 | 09/11/2003 | Manabu Nakamura | 031140 | 3468 |
| 38834 WESTERMAN | 7590 08/10/2007 , HATTORI, DANIELS & ADRIAN, LLP TICUT AVENUE, NW | EXAMINER | | |
| | | | SMITH, B | RADLEY |
| WASHINGTO | N, DC 20036 | | ART UNIT | PAPER NUMBER |
| | | | 2891 | |
| | | | MAIL DATE | DEL MEDV MODE |
| • | | | MAIL DATE | DELIVERY MODE |
| | | | 08/10/2007 | PAPER |

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

| | Application No. | Applicant(s) | | | | |
|---|--|---|--|--|--|--|
| | 10/659,748 | NAKAMURA ET AL. | | | | |
| Office Action Summary | Examiner | Art Unit | | | | |
| | Bradley K. Smith | 2891 | | | | |
| The MAILING DATE of this communication a Period for Reply | appears on the cover sheet wit | th the correspondence address | | | | |
| A SHORTENED STATUTORY PERIOD FOR REF WHICHEVER IS LONGER, FROM THE MAILING - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication If NO period for reply is specified above, the maximum statutory per - Failure to reply within the set or extended period for reply will, by sta Any reply received by the Office later than three months after the ma earned patent term adjustment. See 37 CFR 1.704(b). | DATE OF THIS COMMUNIC 1.136(a). In no event, however, may a re- tiod will apply and will expire SIX (6) MON titute, cause the application to become AB. | CATION. eply be timely filed THS from the mailing date of this communication. ANDONED (35 U.S.C. § 133). | | | | |
| Status | | | | | | |
| 1) Responsive to communication(s) filed on 09 | July 2007. | | | | | |
| 2a) ☐ This action is FINAL . 2b) ☑ T | This action is FINAL . 2b)⊠ This action is non-final. | | | | | |
| 3) Since this application is in condition for allow | wance except for formal matte | ers, prosecution as to the merits is | | | | |
| closed in accordance with the practice unde | er <i>Ex parte Quayle</i> , 1935 C.D. | . 11, 453 O.G. 213. | | | | |
| Disposition of Claims | | | | | | |
| 4)⊠ Claim(s) <u>1-3 and 5-19</u> is/are pending in the | application. | | | | | |
| 4a) Of the above claim(s) is/are withd | 4a) Of the above claim(s) is/are withdrawn from consideration. | | | | | |
| 5) Claim(s) is/are allowed. | | | | | | |
| 6)⊠ Claim(s) <u>1-3 and 5-19</u> is/are rejected. | | | | | | |
| 7) Claim(s) is/are objected to. | | | | | | |
| 8) Claim(s) are subject to restriction and | d/or election requirement. | | | | | |
| Application Papers | | | | | | |
| 9)☐ The specification is objected to by the Exam | iner. | | | | | |
| 10)⊠ The drawing(s) filed on <u>11 September 2003</u> | is/are: a)⊠ accepted or b)□ |] objected to by the Examiner. | | | | |
| Applicant may not request that any objection to t | he drawing(s) be held in abeyan | ce. See 37 CFR 1.85(a). | | | | |
| Replacement drawing sheet(s) including the corr | | • • • | | | | |
| 11) ☐ The oath or declaration is objected to by the | Examiner. Note the attached | Office Action or form PTO-152. | | | | |
| Priority under 35 U.S.C. § 119 | | • | | | | |
| 12)⊠ Acknowledgment is made of a claim for forei a)⊠ All b)☐ Some * c)☐ None of: | ign priority under 35 U.S.C. § | 119(a)-(d) or (f). | | | | |
| Certified copies of the priority docume | 1.⊠ Certified copies of the priority documents have been received. | | | | | |
| <u>-</u> | | | | | | |
| 3. Copies of the certified copies of the p | • | received in this National Stage | | | | |
| • | eau (PCT Rule 17 2(a)) | | | | | |
| application from the International Bure | , | | | | | |
| application from the International Burd * See the attached detailed Office action for a l | , | received. | | | | |
| * See the attached detailed Office action for a l | list of the certified copies not | | | | | |
| * See the attached detailed Office action for a l | list of the certified copies not | received. summary (PTO-413) s)/Mail Date | | | | |

DETAILED ACTION

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 1. Claims 1, 2, 3, 5, 6, 8,11, 12,14, 17 and 18 are rejected under 35 U.S.C. 103(a) as being unpatentable over Wong (US Patent 5,423,944) in view of Dobuzinsky et al (US Patent 5,412,246). Wong disclose forming a first insulation film using a strong acid solution on the face of the substrate. With regards to claims 6 and 12, Wong disclose the use of nitric acid (see column 1 lines 20-25). With regards to claim 8 and 14, Wong disclose the use of ozone in an acidic solution (see column 2 lines 50-65). However Wong fails to disclose forming a second insulation film by low temperature processing and cleaning (removing defects near the surface) the wafer (substrate) (see column 1 lines 20-25 and see column 2 lines 50-65). Whereas Dobuzinsky et al. disclose the formation of a second dielectric layer using low temperature processing. With regards to claims 2 and 3, Dobuzinsky et al. disclose using a low temperature oxidation plasma(see title). With regards to claim 5, Dobuzinsky et al. disclose forming an ONO film (see column lines 55-65). With regards to claims 11, 17 and 18 Dobuzinsky et al. disclose forming gate oxide films(see abstract). Therefore it would have been obvious to one of ordinary skill in the art at the time the invention was made to combine the teachings of Wong and

Art Unit: 2891

Dobuzinsky et al in view of because the oxidizing agents such as nitric acid help remove defects (see Wong column 1 lines 20-25).

- 2. Claims 7, 9,13, 15 and 16 are rejected under 35 U.S.C. 103(a) as being unpatentable over Wong (US Patent 5,423,944) in view of Dobuzinsky et al (US Patent 5,412,246). as applied to claim 3 above, and further in view of Muramatsu et al. (US Patent 6,468,841). Wong and Dobuzinsky et al disclose the forming of two insulation layers. However they fail to teach the use of nitric acid and an ozone containing solution (see above). Whereas Muramatsu disclose the use of nitric acid and an ozone containing solution at temperature of 420 degrees C (see column 10 line 5-16). Therefore it would have been obvious to one of ordinary skill in the art at the time the invention was made to combine the teachings of Wong and Dobuzinsky et al in view of Muramatsu et al. because the oxidizing agents such as nitric acid help remove defects (see Wong column 1 lines 20-25).
- 3. Claim 10 is rejected under 35 U.S.C. 103(a) as being unpatentable over Wong (US Patent 5,423,944) in view of Dobuzinsky et al (US Patent 5,412,246). Dobuzinsky et al and Wong et al. discloses the claimed invention except for the first insulation film has a film thickness of 1nm or more. It would have been obvious to one of ordinary skill in the art at the time the invention was made to make an oxide film greater than one nanometer, because if the dielectric film were less than one nanometer it would lose its dielectric properties. In Gardner v. TEC Systems, Inc., 725 F.2d 1338, 220 USPQ 777 (Fed. cir. 1984), cert. denied, 469 U.S. 830, 225. USPQ 232 (1984), the Federal Circuit held that, where the only difference between the prior art and the claims was a recitation of relative dimensions of the claimed device and a device having the claimed relative

Art Unit: 2891

dimensions would not perform differently than the prior art device, the claimed device was not patentably distinct from the prior art device.

4. Claim 19 is rejected under 35 U.S.C. 103(a) as being unpatentable over Wong (US Patent 5,423,944) in view of Dobuzinsky et al (US Patent 5,412,246). Wong disclose forming a first insulation film using a strong acid solution on the face of the substrate. However Wong fails to disclose forming a second insulation film by low temperature processing after a fixed period of time. Whereas Dobuzinsky et al. disclose the formation of a second 'dielectric layer using low temperature processing after a fixed period of time, and then leaving the second dielectric layer for a fixed period of time. The examiner asserts that since the Dobuzinsky et al. forms the nitride after the oxide is formed inherently there is a fixed period of time and the nitride is left for a fixed period (otherwise distinct layer of silicon oxide and silicon nitride would not have been formed as shown in figure 59. Therefore it would have been obvious to one of ordinary skill in the ad at the time the invention was made to combine the teachings of Wong and Dobuzinsky et al in view of because the oxidizing agents such as nitric acid help remove defects (see Wong column 1 lines 20-25).

Response to Arguments

Applicant's arguments filed 7/9/07 have been fully considered but they are not persuasive. The applicant contends that "Wong does not specify the component of a film corresponding to the first insulation film formed by using the acidic solution". The examiner would like to point out that Wong discloses the use of nitric acid to form a first insulation film (just like the claimed invention does in claim 6). Therefore Wong would inherently form the same insulation film being claimed.

Art Unit: 2891

In addition the applicant contends the insulation layer in Dobuzinsky " is not formed based on insulation layer formed in advance on the substrate30". However, in response to applicant's arguments against the references individually, one cannot show nonobviousness by attacking references individually where the rejections are based on combinations of references. See In re Keller, 642 F.2d 413, 208 USPQ 871 (CCPA 1981); In re Merck & Co., 800 F.2d 1091, 231 USPQ 375 (Fed. Cir. 1986).

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Bradley K. Smith whose telephone number is 571-272-1884. The examiner can normally be reached on 10-6.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Bill Baumeister can be reached on 571-272-1722. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571/-272/-1000.

Application/Control Number: 10/659,748

Art Unit: 2891

Primary Examiner Art Unit 2891 Page 6